

# Elements of Electrical & Electronics Engineering (1313202) - Winter 2024 Solution

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## Question 1(a) [3 marks]

Explain difference between Active and passive network.

### Solution

Active Network	Passive Network
Contains at least one active element (voltage/current source)	Contains only passive elements (R, L, C)
Can deliver energy to the circuit	Cannot deliver energy to the circuit
Can amplify signal power	Cannot amplify signal power

### Mnemonic

“Active Adds Power, Passive Parts Take”

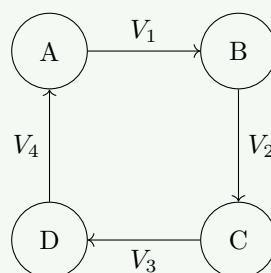
## Question 1(b) [4 marks]

State and explain Kirchhoff's voltage law (KVL).

### Solution

**Statement:** Kirchhoff's Voltage Law (KVL) states that the algebraic sum of all voltages around any closed loop in a circuit is zero.

**Mathematically:**  $V_1 + V_2 + V_3 + V_4 = 0$  or  $\sum V = 0$



### Sign Convention:

- **Voltage Drop:** When passing through a resistor in direction of current, voltage is negative.
- **Voltage Rise:** When passing through a source from negative to positive, voltage is positive.

**Mnemonic**

“Voltage Loop Equals Zero”

**Question 1(c) [7 marks]**

Define the following terms: (1) Charge (2) Current (3) Potential (4) E.M.F. (5) Inductance (6) Capacitance (7) Frequency.

**Solution**

Term	Definition
<b>Charge</b>	The quantity of electricity measured in coulombs (C).
<b>Current</b>	The rate of flow of electric charge measured in amperes (A).
<b>Potential</b>	The electrical pressure or energy per unit charge measured in volts (V).
<b>E.M.F.</b>	Electromotive Force is the energy supplied by a source per unit charge measured in volts (V).
<b>Inductance</b>	The property of an electric circuit that opposes change in current, measured in henries (H).
<b>Capacitance</b>	The ability of a body to store electrical charge, measured in farads (F).
<b>Frequency</b>	Number of complete cycles per second, measured in hertz (Hz).

**Mnemonic**

“Coulombs’ Flow Pressurized by Energy Induces Capacitive Fluctuations”

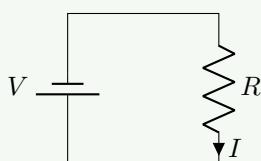
**Question 1(c) OR [7 marks]**

State Ohm’s law. Write its application and limitation.

**Solution**

**Statement:** Ohm’s Law states that the current flowing through a conductor is directly proportional to the potential difference and inversely proportional to the resistance, provided physical conditions (temperature) remain constant.

**Formula:**  $V = I \times R$



Where:  $V$  = Voltage (V),  $I$  = Current (A),  $R$  = Resistance ( $\Omega$ ).

**Applications:**

- Circuit design and analysis.
- Power consumption calculations.
- Component value determination.
- Voltage divider networks.
- Current divider networks.

**Limitations:**

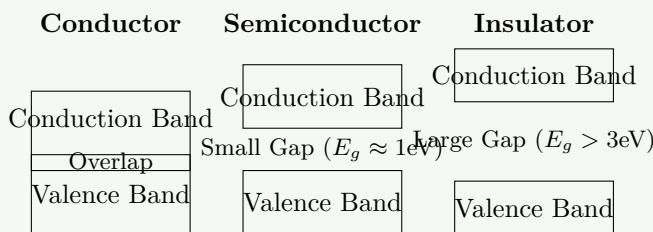
- Valid only for linear components.
- Not applicable to non-ohmic devices (diodes, transistors).
- Invalid at high temperatures.
- Not valid for semiconductors.
- Cannot be applied to non-linear resistive elements.

**Mnemonic**

“Volts Reveal Amps’ Motion”

**Question 2(a) [3 marks]**

Draw and explain energy band diagrams for insulator, conductor and Semiconductor.

**Solution**

- Conductor:** Valence and conduction bands overlap, allowing free electron movement.
- Semiconductor:** Small energy gap (0.7-3 eV) between bands allows limited conduction.
- Insulator:** Large energy gap (> 3 eV) prevents electrons from moving to conduction band.

**Mnemonic**

“Conductors Overlap, Semiconductors Jump Small, Insulators Block All”

**Question 2(b) [4 marks]**

Write statement of Maximum power transfer theorem and reciprocity theorem.

**Solution**

Theorem	Statement
<b>Maximum Power Transfer Theorem</b>	Maximum power is transferred from source to load when the load resistance equals the source internal resistance ( $R_L = R_S$ ).
<b>Reciprocity Theorem</b>	In a linear, bilateral network, if voltage source $E$ in branch 1 produces current $I$ in branch 2, then the same voltage source $E$ in branch 2 will produce the same current $I$ in branch 1.

**Mnemonic**

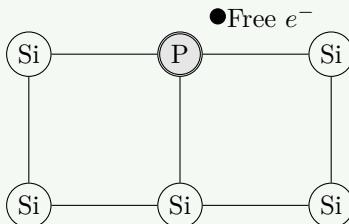
“Match Resistance for Maximum Power; Swap Sources, Current Stays”

**Question 2(c) [7 marks]**

Explain the formation and conduction of N-type materials.

**Solution****Formation Process:**

- Pure silicon/germanium doped with pentavalent impurity atoms (P, As, Sb).
- Impurity atoms have 5 valence electrons (silicon has 4).
- Four electrons form covalent bonds, fifth becomes free electron.
- Creates excess negative charge carriers.

**Conduction Mechanism:**

- Majority Carriers:** Electrons.
- Minority Carriers:** Holes.
- Electron movement provides electrical conduction.
- Even at room temperature, free electrons enable current flow.

**Mnemonic**

"Pentavalent Provides Plus-One Electron"

**Question 2(a) OR [3 marks]**

Define valence band, conduction band and forbidden gap.

**Solution**

Term	Definition
<b>Valence Band</b>	Energy band occupied by valence electrons that are bound to specific atoms in the solid.
<b>Conduction Band</b>	Higher energy band where electrons can move freely throughout the material, enabling electrical conduction.
<b>Forbidden Gap</b>	Energy region between valence and conduction bands where no electron states exist.

**Mnemonic**

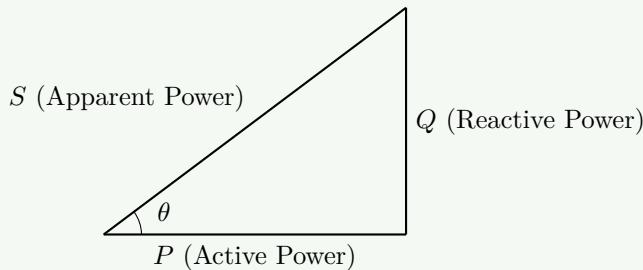
"Valence Bounds, Conduction Flows, Forbidden Gaps Block"

**Question 2(b) OR [4 marks]**

Define the terms active power, reactive power and power factor with power triangle.

**Solution**

**Power Triangle:**



- Active Power (P):** Actual power consumed, measured in watts (W),  $P = VI \cos \theta$ .
- Reactive Power (Q):** Power oscillating between source and load, measured in volt-amperes reactive (VAR),  $Q = VI \sin \theta$ .
- Power Factor:** Ratio of active power to apparent power,  $PF = \cos \theta = P/S$ .

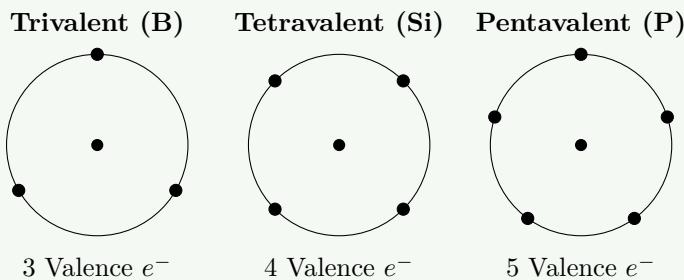
#### Mnemonic

“Real Power Works, Reactive Power Waits”

### Question 2(c) OR [7 marks]

Explain the structure of atom of trivalent, tetravalent and pentavalent elements.

#### Solution



Element	Structure	Examples	Use
Trivalent	3 electrons in outer shell	B, Al, Ga, In	P-type dopant
Tetravalent	4 electrons in outer shell	Si, Ge, C	Semiconductor base
Pentavalent	5 electrons in outer shell	P, As, Sb	N-type dopant

#### Mnemonic

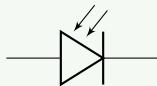
“Three Accepts, Four Forms, Five Donates”

### Question 3(a) [3 marks]

Draw the symbol of photodiode and state its application.

#### Solution

Symbol:

**Figure 1.** Photodiode Symbol**Applications:**

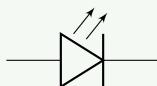
- Light sensors and detectors.
- Optical communication systems.
- Solar cells and photovoltaic applications.
- Camera exposure controls.
- Medical equipment (pulse oximeters).

**Mnemonic**

“Light Triggers Electric Current”

**Question 3(b) [4 marks]**

**Write a Short note on LED.**

**Solution****Symbol:****Figure 2.** LED Symbol**Information:**

- **Structure:** P-N junction diode that emits light when forward biased.
- **Working Principle:** Electron-hole recombination releases energy as photons.
- **Types:** Various colors based on semiconductor material (GaAs, GaP, GaN).
- **Advantages:** Low power consumption, long life, small size, fast switching.
- **Applications:** Displays, indicators, lighting, remote controls, optical communications.

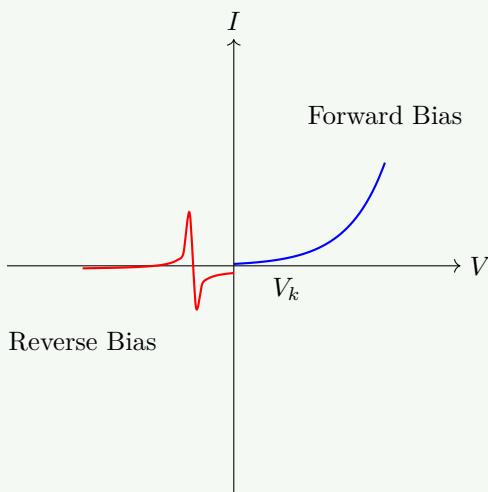
**Mnemonic**

“Electrons Jump, Photons Emit”

**Question 3(c) [7 marks]**

**Draw and explain VI characteristic of PN junction diode.**

**Solution****V-I Characteristics:**



- Forward Bias Region:**

- Diode conducts when voltage exceeds knee/cut-in voltage (0.3V for Ge, 0.7V for Si).
- Current increases exponentially with voltage.
- Low resistance state.

- Reverse Bias Region:**

- Very small leakage current flows.
- Current remains almost constant with increasing reverse voltage.
- Breakdown occurs at high reverse voltage.

### Mnemonic

“Forward Flows Freely, Reverse Resists Rigidly”

## Question 3(a) OR [3 marks]

List the applications of PN junction diode.

### Solution

#### Applications:

- Rectification in power supplies.
- Signal demodulation.
- Logic gates in digital circuits.
- Voltage regulation (with zener diodes).
- Signal clipping and clamping circuits.
- Protection circuits against reverse polarity.

### Mnemonic

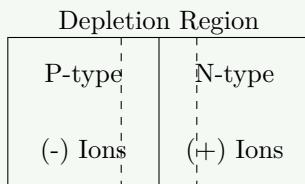
“Rectify, Detect, Clip, Protect”

## Question 3(b) OR [4 marks]

Explain the formation of depletion region in unbiased P-N junction.

**Solution****Formation Process:**

- Electrons from N-side diffuse into P-side.
- Holes from P-side diffuse into N-side.
- Recombination occurs at junction.
- Immobile ions remain (positive in N-side, negative in P-side).
- Electric field develops, opposing further diffusion.
- Equilibrium is established, creating depletion region.

**Mnemonic**

“Diffusion Creates Barrier Field”

**Question 3(c) OR [7 marks]**

Explain construction, working and applications of PN junction diode.

**Solution****Construction:**

- P-type semiconductor joined with N-type semiconductor.
- Made from single crystal of silicon or germanium.
- Metal contacts connected to P and N regions.

**Working:**

- **Forward Bias:** Positive to P, negative to N. Depletion region narrows. Current flows when voltage exceeds barrier potential.
- **Reverse Bias:** Positive to N, negative to P. Depletion region widens. Only small leakage current flows.

**Applications:** Power rectification, Signal detection, Voltage regulation, Switching, Protection circuits.

**Mnemonic**

“Join P-N, Control Current Direction”

**Question 4(a) [3 marks]**

Define: (1) Ripple frequency (2) Ripple factor (3) PIV of a diode.

**Solution**

Term	Definition
<b>Ripple Frequency</b>	Frequency of the AC component remaining in the rectified DC output ( $2 \times$ input frequency for full-wave, $1 \times$ for half-wave).
<b>Ripple Factor</b>	Ratio of RMS value of AC component to the DC component in rectifier output ( $\gamma = V_{ac(rms)} / V_{dc}$ ).
<b>PIV of a diode</b>	Peak Inverse Voltage is the maximum reverse voltage a diode can withstand without breakdown.

**Mnemonic**

“Frequency Fluctuates, Factor Measures, PIV Protects”

**Question 4(b) [4 marks]**

Give comparison between full wave rectifier with two diodes and full wave bridge rectifier.

**Solution**

Parameter	Center-Tapped Full Wave	Bridge Rectifier
<b>Number of Diodes</b>	2	4
<b>Transformer</b>	Center-tapped required	Simple transformer
<b>PIV</b>	$2V_m$	$V_m$
<b>Efficiency</b>	81.2%	81.2%
<b>Ripple Factor</b>	0.48	0.48
<b>Output</b>	$V_m/\pi$	$2V_m/\pi$
<b>Cost</b>	Higher transformer cost	Higher diode cost

**Mnemonic**

“Two Diodes Tap Center, Four Make Bridge”

**Question 4(c) [7 marks]**

Explain zener diode as voltage regulator.

**Solution**

Circuit Diagram:

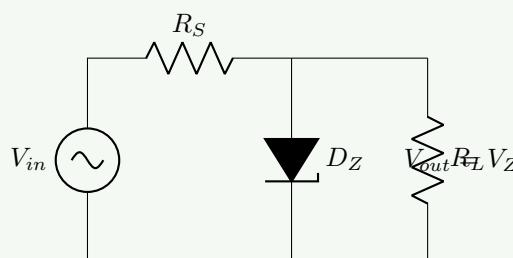


Figure 3. Zener Voltage Regulator

Working Principle:

- Zener diode operates in reverse breakdown region.
- Maintains constant voltage across its terminals.
- Acts as voltage reference.

**Circuit Operation:**

- Series resistor  $R_S$  limits current.
- Zener conducts when input exceeds breakdown voltage.
- Excess current flows through zener diode.
- Output voltage remains constant at zener voltage.

**Advantages:** Simple circuit, Low cost, Good regulation for small load changes.

**Mnemonic**

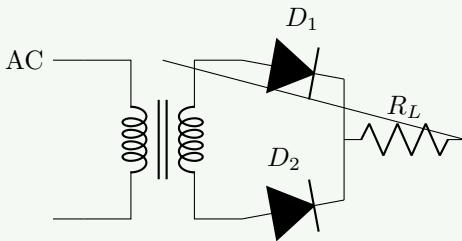
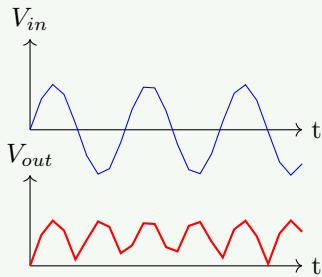
“Zener Breaks Down to Hold Voltage Steady”

**Question 4(a) OR [3 marks]**

What is rectifier? Explain full wave rectifier with waveforms.

**Solution**

**Rectifier:** A circuit that converts AC voltage to pulsating DC voltage.

**Full Wave Rectifier (Center-Tapped):****Waveforms:**

**Figure 4.** Full Wave Rectifier Waveforms

**Mnemonic**

“Both Half-Cycles Become Positive”

**Question 4(b) OR [4 marks]**

Why filter is required in rectifier? State the different types of filter and explain any one type of filter.

### Solution

#### Need for Filter:

- Rectifier output contains AC ripple component.
- Pure DC required for electronic circuits.
- Filters smooth pulsating DC by removing AC components.

**Types of Filters:** Capacitor (C), Inductor (L), LC,  $\pi$  ( $\Pi$ ), CLC filter.

#### Capacitor Filter:

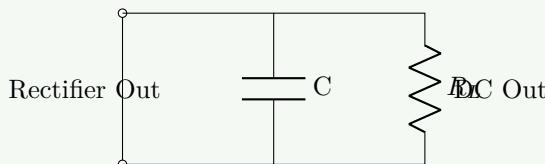


Figure 5. Capacitor Filter

#### Working:

- Capacitor charges during voltage rise.
- Discharges slowly during voltage fall.
- Reduces ripple voltage.

### Mnemonic

“Capacitor Catches Peaks, Releases Slowly”

## Question 4(c) OR [7 marks]

Write the need of rectifier. Explain bridge rectifier with circuit diagram and draw its input and output waveforms.

### Solution

**Need of Rectifier:** Convert AC to DC for electronic devices, power supplies, charging systems.

#### Bridge Rectifier Circuit:

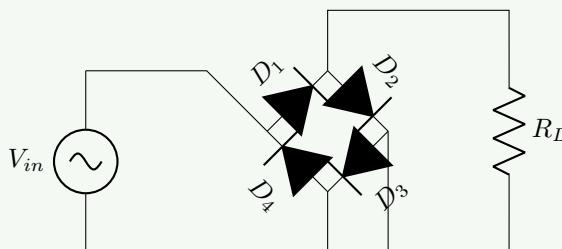


Figure 6. Bridge Rectifier

**Waveforms:** Input is sine wave, Output is pulsating DC (full-wave rectified).

### Mnemonic

“Four Diodes Direct All Current One Way”

## Question 5(a) [3 marks]

Explain causes of electronic waste.

**Solution****Causes:**

- Rapid technological advancement.
- Planned obsolescence of products.
- Decreasing product lifespan.
- Consumer behavior preferring new devices.
- Limited repair options for electronics.
- High repair costs compared to replacement.

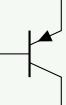
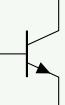
**Mnemonic**

“Technology Advances, Products Expire Rapidly”

**Question 5(b) [4 marks]**

Compare PNP and NPN transistors.

**Solution**

Parameter	PNP Transistor	NPN Transistor
Symbol		
Majority Carriers	Holes	Electrons
Current Flow	Emitter to Collector	Collector to Emitter
Biassing	Emitter +ve, Base -ve	Collector +ve, Base +ve
Switching Speed	Slower	Faster

**Mnemonic**

“Negative-Positive-Negative vs Positive-Negative-Positive”

**Question 5(c) [7 marks]**

Draw the symbol, explain the construction and working of MOSFET.

**Solution**

Symbol:

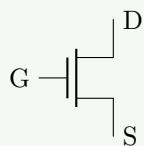


Figure 7. MOSFET Symbol

Construction:

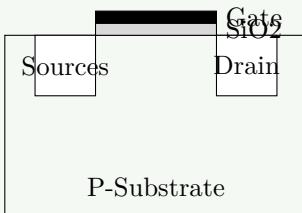


Figure 8. MOSFET Construction

**Working Principle (Enhancement Mode):**

- No channel exists without gate voltage.
- Positive gate voltage attracts electrons from substrate.
- Induced channel allows current flow from drain to source.
- Increasing gate voltage enhances conductivity.

**Mnemonic**

“Gate Voltage Creates Electron Channel”

**Question 5(a) OR [3 marks]**

Explain methods to handle electronic waste.

**Solution**

	<b>Method</b>	<b>Description</b>
<b>Methods:</b>	<b>Reduce</b>	Designing longer-lasting electronics.
	<b>Reuse</b>	Donating or selling functional devices.
	<b>Recycle</b>	Material recovery (precious metals).
	<b>Regulation</b>	E-waste management policies.
	<b>Recovery</b>	Extracting valuable materials.

**Mnemonic**

“Reduce, Reuse, Recycle, Regulate, Recover”

**Question 5(b) OR [4 marks]**

Derive the relationship between  $\alpha_{dc}$  and  $\beta_{dc}$ .

**Solution**

**Relations:**  $I_E = I_C + I_B$ ,  $\alpha_{dc} = I_C/I_E$ ,  $\beta_{dc} = I_C/I_B$ .

**Derivation:**

- From  $I_E = I_C + I_B$ , divide by  $I_C$ :

$$\begin{aligned}\frac{I_E}{I_C} &= 1 + \frac{I_B}{I_C} \\ \frac{1}{\alpha_{dc}} &= 1 + \frac{1}{\beta_{dc}} \\ \frac{1}{\alpha_{dc}} &= \frac{\beta_{dc} + 1}{\beta_{dc}}\end{aligned}$$

$$\alpha_{dc} = \frac{\beta_{dc}}{1 + \beta_{dc}}$$

- Rearranging for  $\beta_{dc}$ :

$$\beta_{dc} = \frac{\alpha_{dc}}{1 - \alpha_{dc}}$$

### Mnemonic

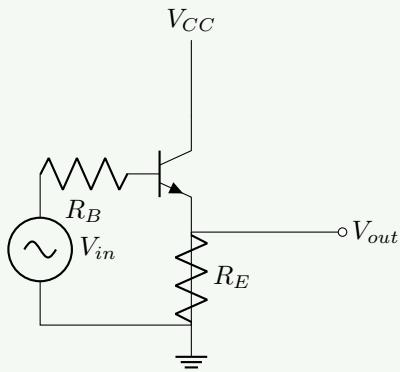
“Alpha-Beta Relate as Alpha = Beta/(1+Beta)”

## Question 5(c) OR [7 marks]

Explain common collector configuration with its input and output characteristics.

### Solution

**Common Collector (Emitter Follower):**



**Figure 9.** Common Collector Circuit

### Characteristics:

- Input Characteristics:** Plot of  $I_B$  vs  $V_{BC}$ . High input impedance.
- Output Characteristics:** Plot of  $I_E$  vs  $V_{CE}$ . Low output impedance.

**Key Features:** Voltage gain  $\approx 1$ , High current gain ( $\beta + 1$ ), used as buffer.

### Mnemonic

“Emitter Follows Base Voltage”